



isc Silicon NPN Power Transistor

DESCRIPTION

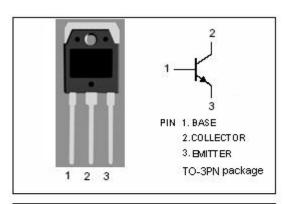
- · High Breakdown Voltage-
 - : V_{(BR)CBO}= 800V(Min)
- · Fast Switching Speed
- · Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

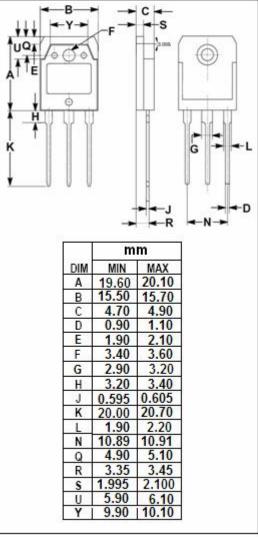
APPLICATIONS

· Designed for switching regulator applications

ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	800	V	
V _{CEO}	Collector-Emitter Voltage	500	V	
V _{EBO}	Emitter-Base Voltage	7	V	
Ic	Collector Current-Continuous	4	А	
Ісм	Collector Current-Peak 8		А	
I _B	Base Current-Continuous	Current-Continuous 1.5		
P _C	Collector Power Dissipation @ T _a =25°C	2.5	W	
	Collector Power Dissipation @ T _C =25°C	60		
TJ	Junction Temperature	150	$^{\circ}$ C	
T _{stg}	Storage Temperature Range -55~150		$^{\circ}$ C	







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2SC3088

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(\text{BR})\text{CEO}}$	Collector-Emitter Breakdown Voltage	I_C = 1mA; R_{BE} = ∞	500			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	800			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	7			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 1.5A; I _B = 0.3A			1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 1.5A; I _B = 0.3A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 500V; I _E =0			10	μ А
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C =0			10	μ А
h _{FE-1}	DC Current Gain	I _C = 0.3A; V _{CE} = 5V	15		50	
h _{FE-2}	DC Current Gain	I _C = 1.5A; V _{CE} = 5V	8			
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} =1.0MHz		40		pF
f⊤	Current-Gain—Bandwidth Product	I _C = 0.3A; V _{CE} = 10V		18		MHz
Switching times						
ton	Turn-on Time				1.0	μ S
t _{stg}	Storage Time	I_C = 2A , I_{B1} = - I_{B2} = -0.4A; R_L = 100 Ω ; V_{CC} = 200V			3.0	μS
t _f	Fall Time	,			1.0	μS

♦ h_{FE-1} Classifications

L	М	N
15-30	20-40	30-50

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